

11th European Symposium on Semiconductor Detectors

Monday, 8 June 2009

New Detector Devices - APS - Main Auditorium (11:40 - 13:10)

time	[id] title	presenter
11:40	[34] Improved radiation tolerance of MAPS using a depleted epitaxial layer	DOROKHOV, Andrei
12:00	[35] Development of Fast and Radiation Tolerant Monolithic Active Pixel Sensors With Column Parallel Readout	KOZIEL, Michal
12:20	[36] Radiation Hard CMOS Monolithic Pixels for Electron Microscopy	CONTARATO, Devis
12:40	[37] Progress in Development of Monolithic Active Pixel Sensor in SOI Technology	KUCEWICZ, Wojciech